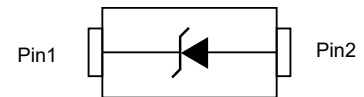


## Description

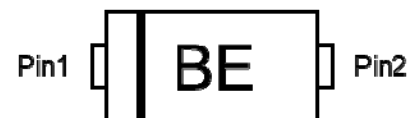
The PESDHC5D3V3U protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical.

## Feature

- 250W peak pulse power per line ( $t_P = 8/20\mu s$ )
- SOD-523 package
- Replacement for MLV(0603)
- Unidirectional configurations
- Response time is typically  $< 1\text{ ns}$
- Protect one I/O or power line
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to  
IEC 61000-4-2(ESD)  $\pm 30\text{KV}$ (air),  $\pm 30\text{KV}$ (contact);  
IEC 61000-4-4 (EFT) 40A (5/50ns)



**Circuit Diagram**



**Marking (Top View)**

## Mechanical Characteristics

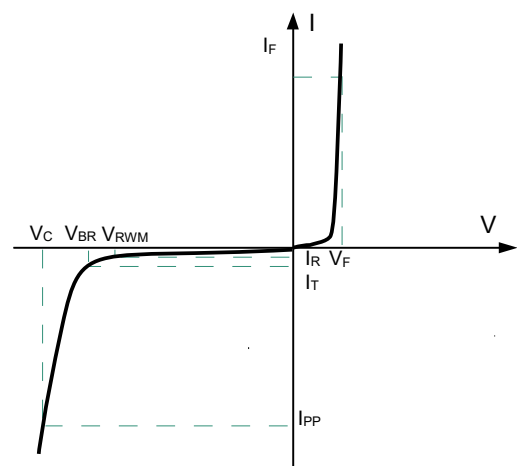
- Lead finish: 100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:  $260^\circ\text{C}$
- Device meets MSL 1 requirements
- Pure tin plating:  $7 \sim 17\text{ }\mu\text{m}$
- Pin flatness:  $\leq 3\text{mil}$

## Applications

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

## Electronics Parameter

Symbol	Parameter
$V_{RWM}$	Peak Reverse Working Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$P_{PP}$	Peak Pulse Power
$C_J$	Junction Capacitance
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



## Electrical characteristics per line@25°C ( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Stand-off Voltage	$V_{RWM}$				3.3	V
Reverse Breakdown Voltage	$V_{BR}$	$I_t = 1\text{mA}$	5			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 3.3\text{V}$ $T = 25^\circ\text{C}$			1	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A}$ $t_P = 8/20\mu\text{s}$			6.4	V
Clamping Voltage	$V_C$	$I_{PP} = 5\text{A}$ $t_P = 8/20\mu\text{s}$			7.3	V
Clamping Voltage	$V_C$	$I_{PP} = 15\text{A}$ $t_P = 8/20\mu\text{s}$			8.9	V
Junction Capacitance	$C_j$	$V_R = 0\text{V}$ $f = 1\text{MHz}$		230		pF

## Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Unidirectional Peak Pulse Power ( $t_P = 8/20\mu\text{s}$ )	$P_{PP}$	250	W
Operating Temperature	$T_J$	-55 to +150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-55 to +150	$^\circ\text{C}$

## Typical Characteristics

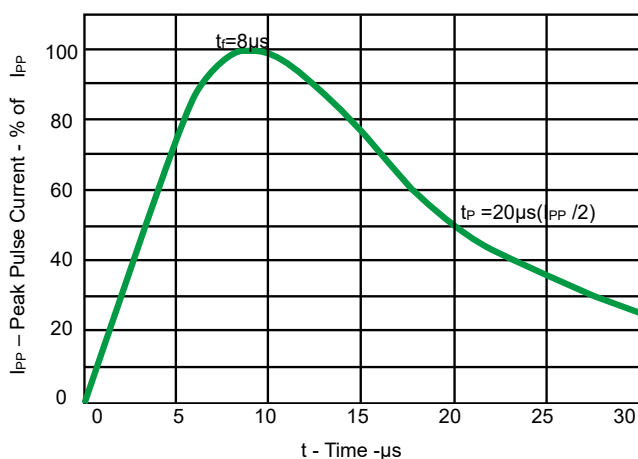


Fig 1. Pulse waveform

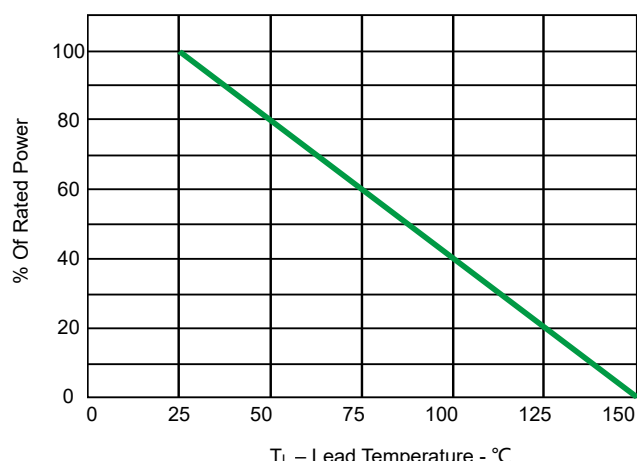


Fig 2. Power derating curve

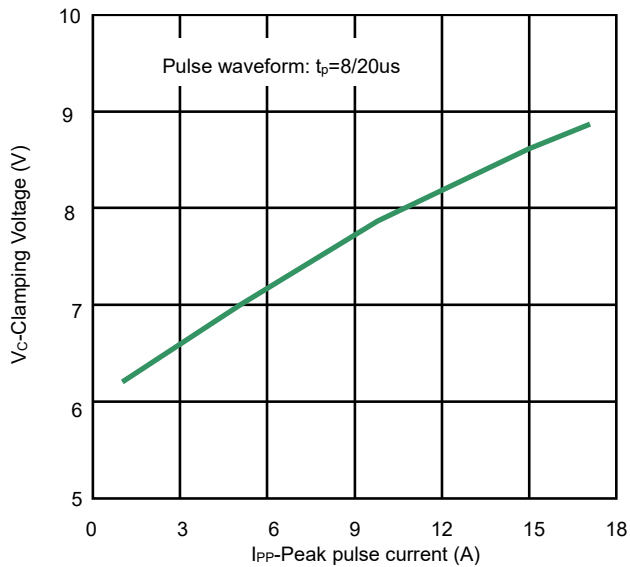


Fig 3. Clamping voltage vs. Peak pulse current

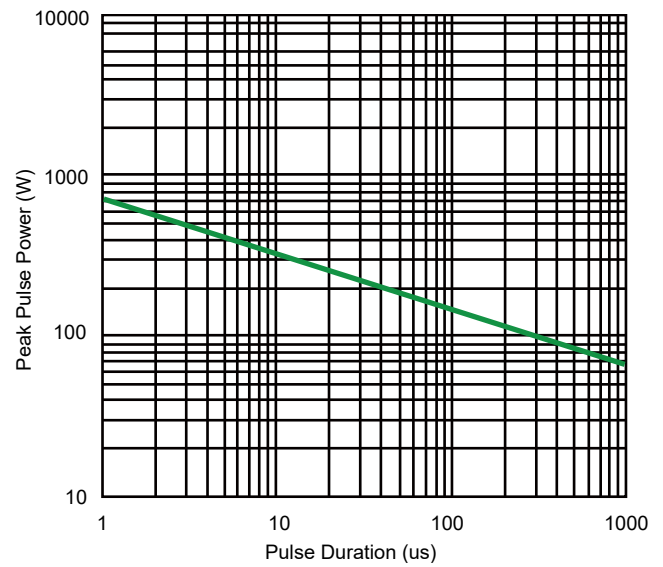
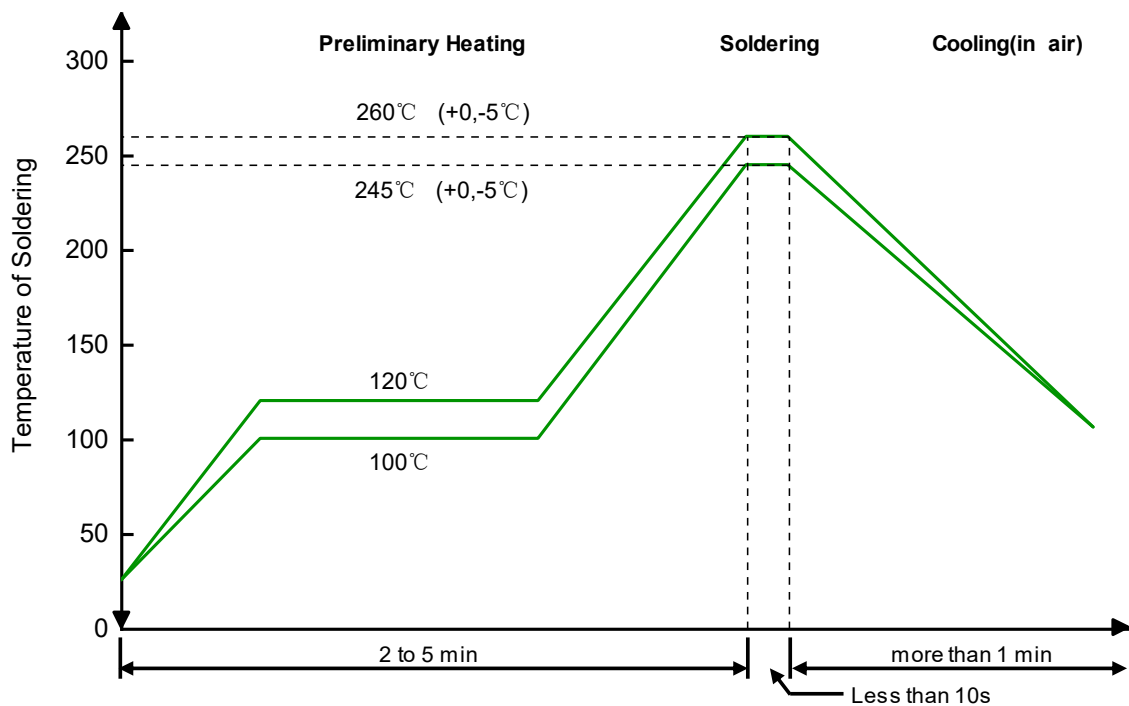


Fig 4. Non repetitive peak pulse power vs. Pulse time

## Solder Reflow Recommendation



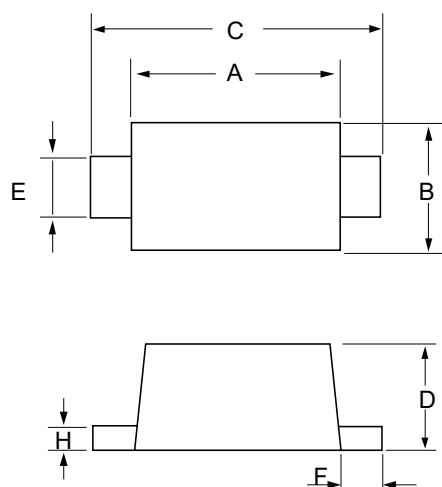
Remark: Pb free for 260°C; Pb for 245°C.

## PCB Design

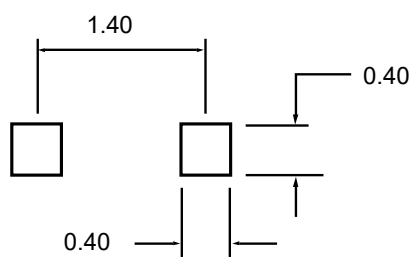
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

## Product dimension (SOD-523)



Dim	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.043	0.051	1.10	1.30
B	0.028	0.035	0.70	0.90
C	0.059	0.067	1.50	1.70
D	0.020	0.028	0.50	0.70
E	0.010	0.014	0.25	0.35
F	0.006	0.010	0.15	0.25
H	0.0028	0.0079	0.07	0.20



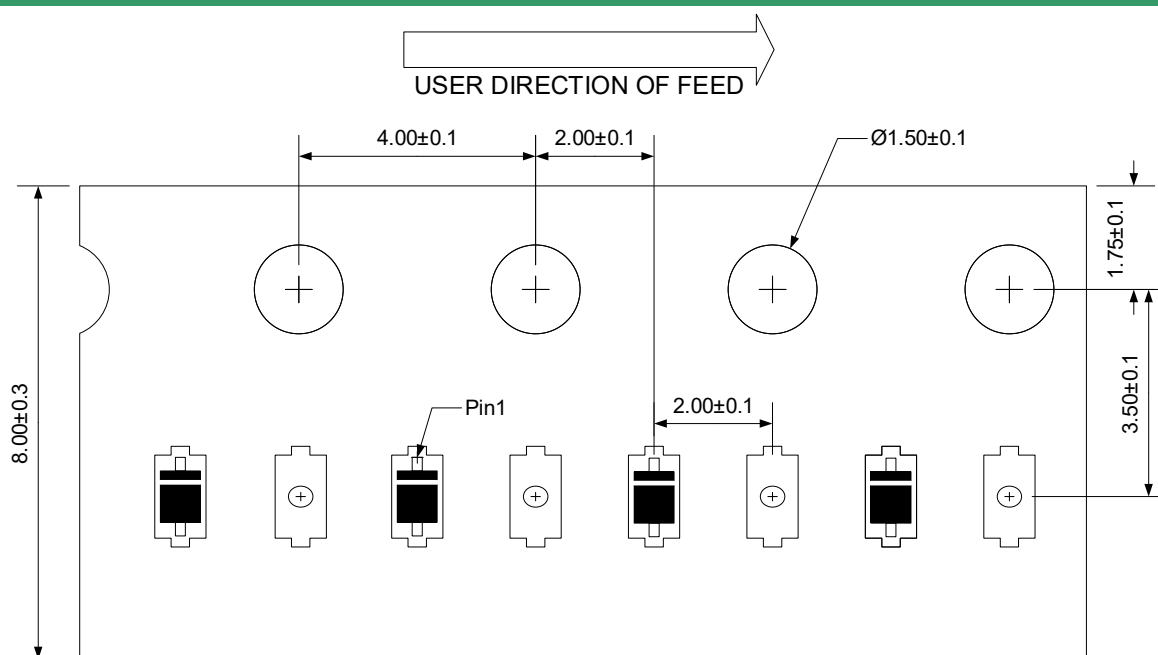
Unit: mm

Suggested PCB Layout

## Ordering information


Device	Package	Shipping
PESDHC5D3V3U	SOD-523	3000 / Tape & Reel

## Load with information



Unit:mm


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